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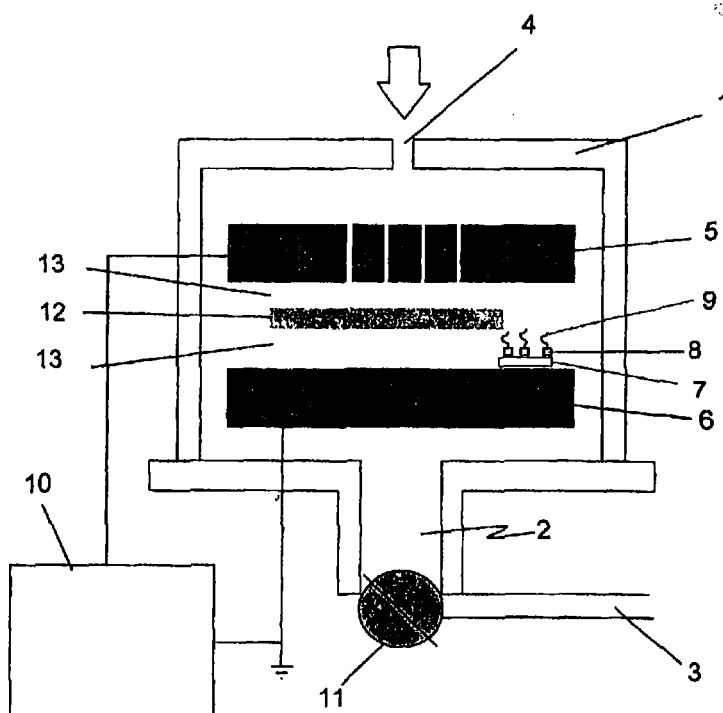
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(54) Title: PRODUCTION OF CARBON NANOTUBES



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(57) Abstract: A method of forming carbon nanotubes by plasma enhanced chemical vapour deposition using a carbon containing gas plasma, wherein the carbon nanotubes are not formed on a substrate at a temperature 300 °C or above.

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